Preferred Device

SOD-123 Schottky Barrier Diodes

The MMSD301T1, and MMSD701T1 devices are spin-offs of our popular MMBD301LT1, and MMBD701LT1 SOT-23 devices. They are designed for high-efficiency UHF and VHF detector applications. Readily available to many other fast switching RF and digital applications.

Features

- Extremely Low Minority Carrier Lifetime
- Very Low Capacitance
- Low Reverse Leakage
- Pb-Free Packages are Available

MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Reverse Voltage	MMSD301T1 MMSD701T1	V _R	30 70	Vdc
Forward Current (DC) Continous		IF	200	mA
Forward Power Dissipation T _A = 25°C		P _F	225	mW
Junction Temperature		TJ	-55 to +125	°C
Storage Temperature Range		T _{stg}	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



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SOD-123 CASE 425 STYLE 1

MARKING DIAGRAM



xx = Specific Device Code XT = MMSD301T1 XH = MMSD701T1

M = Date Code

= Pb-Free Package(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
MMSD301T1	SOD-123	3000 Tape & Reel
MMSD301T1G	SOD-123 (Pb-Free)	3000 Tape & Reel
MMSD701T1	SOD-123	3000 Tape & Reel
MMSD701T1G	SOD-123 (Pb-Free)	3000 Tape & Reel

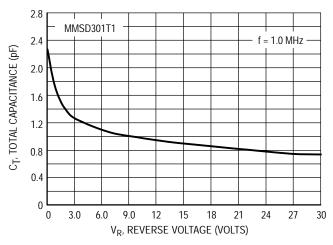
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteris	Symbol	Min	Тур	Max	Unit	
Reverse Breakdown Voltage (I _R = 10 μA)	MMSD301T1 MMSD701T1	V _{(BR)R}	30 70		-	V
Diode Capacitance (V _R = 0 V, f = 1.0 MHz	MMSD301T1 MMSD701T1	C _T	- -	0.9 0.5	1.5 1.0	pF
Total Capacitance $(V_R = 15 \text{ V}, f = 1.0 \text{ MHz})$ $(V_R = 20 \text{ V}, f = 1.0 \text{ MHz})$	MMSD301T1 MMSD701T1	Ст	- -	0.9 0.5	1.5 1.0	pF
Reverse Leakage (V _R = 25 V) (V _R = 35 V)	MMSD301T1 MMSD701T1	I _R	- -	13 9.0	200 200	nAdc nAdc
Forward Voltage (I _F = 1.0 mAdc) (I _F = 10 mA) (I _F = 1.0 mAdc) (I _F = 1.0 mAdc)	MMSD301T1 MMSD701T1	V _F	- - - -	0.38 0.52 0.42 0.7	0.45 0.6 0.5 1.0	Vdc

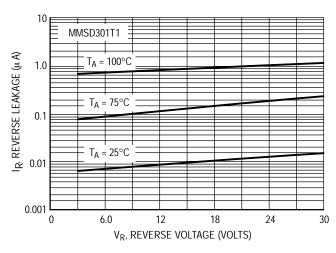
TYPICAL CHARACTERISTICS MMSD301T1



500 MMSD301T1 $\boldsymbol{\tau}$, MINORITY CARRIER LIFETIME (ps) 400 KRAKAUER METHOD 300 200 100 10 20 50 70 90 100 0 IF, FORWARD CURRENT (mA)

Figure 1. Total Capacitance

Figure 2. Minority Carrier Lifetime



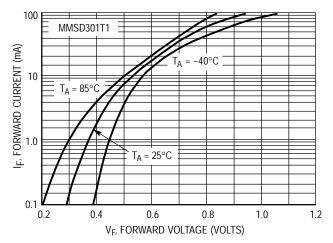
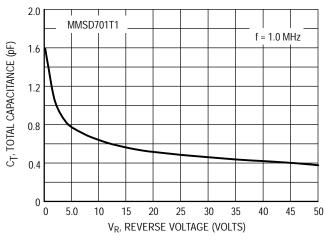


Figure 3. Reverse Leakage

Figure 4. Forward Voltage

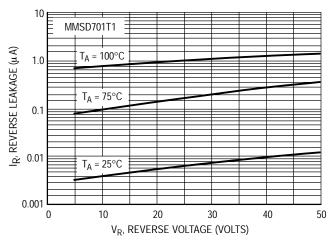
TYPICAL CHARACTERISTICS MMSD701T1



500 MMSD701T1 τ , MINORITY CARRIER LIFETIME (ps) 400 KRAKAUER METHOD 300 200 100 10 20 30 100 0 40 50 70 90 I_F, FORWARD CURRENT (mA)

Figure 5. Total Capacitance

Figure 6. Minority Carrier Lifetime



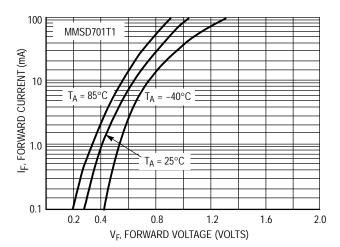
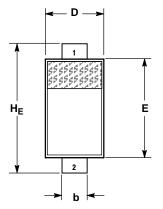


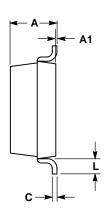
Figure 7. Reverse Leakage

Figure 8. Forward Voltage

PACKAGE DIMENSIONS

SOD-123 CASE 425-04 ISSUE E



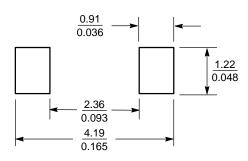


- DIMENSIONING AND TOLERANCING PER ANSI
- 2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.94	1.17	1.35	0.037	0.046	0.053	
A1	0.00	0.05	0.10	0.000	0.002	0.004	
b	0.51	0.61	0.71	0.020	0.024	0.028	
С			0.15			0.006	
D	1.40	1.60	1.80	0.055	0.063	0.071	
E	2.54	2.69	2.84	0.100	0.106	0.112	
HE	3.56	3.68	3.86	0.140	0.145	0.152	
L	0.25			0.010			

STYLE 1: PIN 1. CATHODE 2 ANODE

SOLDERING FOOTPRINT*



mm SCALE 10:1

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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